

Tunable band structure in coreshell quantum dots through alloying of the core

<u>A. Guille</u> | D. Mourad | T. Aubert | A. Houtepen | R. Van Deun | E. Brainis | Z. Hens



Semiconductor nanocrystals

- \rightarrow High tunability
- → Different materials available (CdSe, PbSe, CdS, ZnS,...)
- → Influence of size (quantum confinement)
- \rightarrow Possibility to synthesize core/shell structures





Additional degree of freedom : Composition



Tunability of CdS_(1-x)Se_x\ZnSe QDs

- \rightarrow Homogeneously alloyed CdS_(1-x)S_x core
- ightarrow Tuning of overlap of charge carriers wavefunctions
- \rightarrow Single exciton gain demonstrated in Type II CdS / ZnSe



Quantum dots as gain medium : Advantages of type II QDs



 \rightarrow Gain requires more than one exciton per dot : High excitation fluence



→ Reduced reabsorption : **Reduced excitation fluence**

Overlap of charge carriers

- \rightarrow Valence band-offset CdS_(1-x)S_x \ ZnSe
- \rightarrow Calculated numerically with tight binding approach (D. Mourad)
- \rightarrow From type II to type I 1/2





0.8

0.7

0.6

0.5

0.4

0.3

0.2

N 1

Overlap of charge carriers and gain threshold

ightarrow Calculation in effective mass approximation with calculated band offsets



Electron-hole overlap

Gain threshold



Threshold 4.5 3.5 (E) 2.5 1.5 0.5 0.5 1.5 3.5 4.5 1 2 2.5 3 4 H(nm)





QDs synthesis and characterisation

Results and discussion

Conclusion

2. Synthesis



Hot injection synthesis of CdS_(1-x)Se_x QDs

T. Aubert et al., Chem. Mater. 2013, 25, 2388–2390

- \rightarrow Precursors:
 - Se powder dispersed in ODE
 - S dissolved in ODE
 - Cd oleate
- \rightarrow Balanced reactivity of S and Se precursors
- \rightarrow Composition measured by EDX
- ightarrow Alloying checked with Raman spectroscopy





2. Synthesis



Growth of ZnSe shell

- $\rightarrow\,$ Cores in ODE and octade cylamine
- $\rightarrow\,$ Continuous injection of Zn oleate and TOP-Se
- \rightarrow Stored in hexane

Core



CdS_{0.6}Se_{0.4}

Core-shell



 $CdS_{0.6}Se_{0.4}$ / ZnSe

2. Characterisation



Absorption and emission spectra



- \rightarrow Core radius: 1.5 nm
- \rightarrow Shell thickness: 1.5 nm
- \rightarrow Trap emission in S rich core QDs

Excitonic peak appears in Se rich cores Transition from type II to type I 1/2





Origin of trap emission in CdS/ZnSe

- \rightarrow Larger cores : trap emission visible
- \rightarrow Different PLE spectra and decays

Increased absorption : Effect on gain ?







QDs synthesis and characterisation

Results and discussion

Conclusion

3. Results and discussion



Transient absorption spectroscopy

 \rightarrow Absorption spectrum at different pump-probe delays



3. Results and discussion



Transition Type II to type I 1/2



3. Results and discussion



Absorption spectrum of excited QDs : Optical gain





QDs synthesis and characterisation

Results and discussion

Conclusion

4. Conclusion

Synthesis of CdS_(1-x)Se_x / ZnSe QDs

- ightarrow Absorption and emission from traps at the interface
- → Excess of absorbance at the emission wavelength : synthesis to improve

Tunability of QDs band structure

- \rightarrow Continuous transition from type II to type I ½ demonstrated
- \rightarrow Very large tunability of emission wavelength and overlap
- ightarrow Gain observed with transient absorption spectroscopy











Thank you for your attention !





belgian Science Policy Office











belspo

Belgian Science Policy Office